SN55173, SN65173, SN75173 **QUADRUPLE DIFFERENTIAL LINE RECEIVERS**

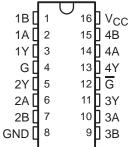
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- Meet or Exceed the Requirements of TIA/EIA-422-B, TIA/EIA-423-B, and TIA/EIA-485-A and ITU Recommendations V.10, V.11, X.26, and X.27
- **Designed for Multipoint Bus Transmission** on Long Bus Lines in Noisy Environments
- **3-State Outputs**
- Common-Mode Input Voltage Range of -12 V to 12 V
- Input Sensitivity . . . ±200 mV
- Input Hysteresis . . . 50 mV Typ
- High Input Impedance . . . 12 k Ω Min
- **Operate From Single 5-V Supply**
- **Low Power Requirements**
- Pin-to-Pin Replacement for AM26LS32

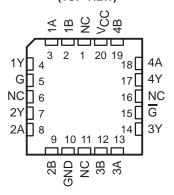
description

The SN55173, SN65173, and SN75173 are monolithic quadruple differential line receivers with 3-state outputs. They are designed to meet requirements of TIA/EIA-422-B, TIA/EIA-423-B, TIA/EIA-485-A, and several ITU recommendations. The standards are for balanced multipoint bus transmission at rates up to 10 megabits per second. The four receivers share two OR enable inputs, one active when high, the other active when low. These devices feature high input impedance, input hysteresis for increased noise immunity, and input sensitivity of ±200 mV over a common-mode input voltage range of -12 V to 12 V. Fail-safe design specifies that if the inputs are open circuited, the outputs are always high. The SN65173 and SN75173 are designed for optimum performance when used with the SN75172 or SN75174 quad differential line drivers.

SN55173...J PACKAGE SN65173, SN75173 . . . D OR N PACKAGE (TOP VIEW)



SN55173 . . . FK PACKAGE (TOP VIEW)



NC-No internal connection

THE SN55173 IS NOT RECOMMENDED FOR NEW DESIGNS.

The SN55173 is characterized over the full military temperature range of -55°C to 125°C. The SN65173 is characterized for operation from -40°C to 85°C. The SN75173 is characterized for operation from 0°C to 70°C.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.



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AVAILABLE OPTIONS

	PACKAGED DEVICES					
TA	PLASTIC SMALL OUTLINE (D)	PLASTIC CHIP CARRIER (FK)	CERAMIC DIP	PLASTIC DIP (N)		
0°C to 70°C	SN75173D	_	_	SN75173N		
-40°C to 85°C	SN65173D	_	_	SN65173N		
−55°C to 125°C	_	SN55173FK	SN55173J	_		

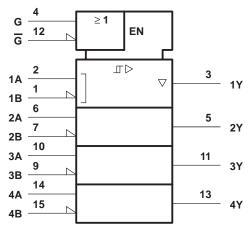
The D package is available taped and reeled. Add the suffix R to the device type (e.g., SN75173DR).

FUNCTION TABLE (each receiver)

DIFFERENTIAL	ENA	BLES	OUTPUT
A–B	G	G	Y
V > 0.2 V	Н	Х	Н
V _{ID} ≥ 0.2 V	Х	L	Н
0.2 \/ 4 \/ 15 4 0.2 \/	Н	Х	?
$-0.2 \text{ V} < \text{V}_{\text{ID}} < 0.2 \text{ V}$	Х	L	?
V _{ID} ≤ -0.2 V	Н	Х	L
V D ≤ -0.2 V	Х	L	L
X	L	Н	Z
Open circuit	Х	L	Н
Open circuit	Н	X	Н

H = high level, L = low level, ? = indeterminate, X = irrelevant, Z = high impedance (off)

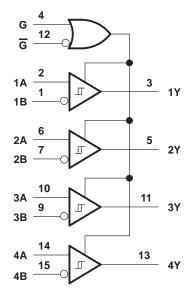
logic symbol †



 \dagger This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12. Pin numbers shown are for the D, J, and N packages.

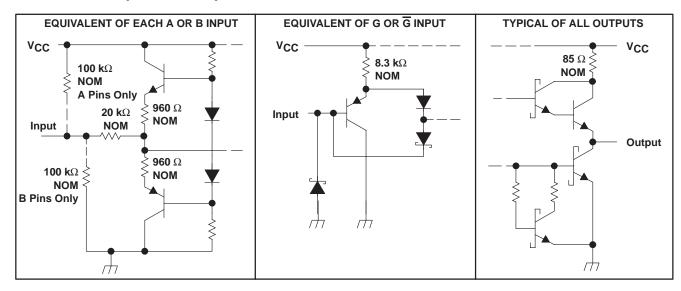


logic diagram (positive logic)



Pin numbers shown are for the D, J, and N packages.

schematics of inputs and outputs



SN55173, SN65173, SN75173 QUADRUPLE DIFFERENTIAL LINE RECEIVERS

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absolute maximum ratings over operating free-air temperature range (unless otherwise noted)† Input voltage (V_I or B inputs)±25 V Differential input voltage, V_{ID} (see Note 2)±25 V Low-level output current, IOL 50 mA

- implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability. NOTES: 1. All voltage values, except differential input voltage, are with respect to network ground terminal.
 - 2. Differential input voltage is measured at the noninverting input with respect to the corresponding inverting input.
 - 3. The package thermal impedance is calculated in accordance with JESD 51.

DISSIPATION RATING TABLE

PACKAGE	$T_{\mbox{\scriptsize A}} \le 25^{\circ}\mbox{\scriptsize C}$ POWER RATING	DERATING FACTOR	T _A = 70°C POWER RATING	T _A = 125°C POWER RATING
FK	1375 mW	11 mW/°C	880 mW	275 mW
J	1375 mW	11 mW/°C	880 mW	275 mW

recommended operating conditions

		MIN	NOM	MAX	UNIT
Supply voltage Vee	SN55173		5	5.5	V
Supply voltage, VCC	SN65173, SN75173		5	5.25	V
Common-mode input voltage, V _{IC}				±12	V
Differential input voltage, V _{ID}				±12	V
High-level enable-input voltage, VIH		2			V
Low-level enable-input voltage, V _{IL}				0.8	V
High-level output current, IOH				-400	μΑ
Low-level output current, I _{OL}				16	mA
	SN55173	-55		125	
Operating free-air temperature, TA	SN65173	-40		85 °C	
	SN75173	0		70	



Storage temperature range, T_{stq}-65°C to 150°C † Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not

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electrical characteristics over recommended ranges of common-mode input voltage, supply voltage, and operating free-air temperature

	PARAMETER	TES	T CONDITIONS		MIN	TYP [†]	MAX	UNIT
V _{IT+}	Positive-going input threshold voltage	$V_0 = 2.7 V$,	$I_0 = -0.4 \text{ mA}$				0.2	V
V _{IT} _	Negative-going input threshold voltage	$V_0 = 0.5 V$,	$I_O = 16 \text{ mA}$		-0.2‡			V
V _{hys}	/ _{hys} Hysteresis (V _{IT+} – V _{IT}) See Figure 4			50		mV		
VIK	Enable-input clamp voltage	$I_{I} = -18 \text{ mA}$					-1.5	V
				SN55173	2.5			V
VOH	High-level output voltage	V _{ID} = 200 mV,	$I_{OH} = -400 \mu A$	SN65173, SN75173	2.7			V
Va.	Landard advisor and the second	Soo Figure 1	$I_{OL} = 8 \text{ mA}$			0.45	V	
VOL	Low-level output voltage	$V_{ID} = -200 \text{ mV},$ See Figure 1	I _{OL} = 16 mA			0.5		
I _{OZ}	High-impedance-state output current	$V_0 = 0.4 \text{ V to } 2.4 \text{ V}$				±20	μΑ	
1.	Line input current	Other input at 0 V,	See Note 3	V _I = 12 V			1	mA
'	Line input current	Other input at 0 v,	See Note 3	V _I = -7 V			-0.8	IIIA
lιΗ	High-level enable-input current	V _{IH} = 2.7 V					20	μΑ
I _{IL}	Low-level enable-input current	V _{IL} = 0.4 V					-100	μΑ
rį	Input resistance				12		, and the second	kΩ
los	Short-circuit output current				-15		-85	mA
Icc	Supply current	Outputs disabled					70	mA

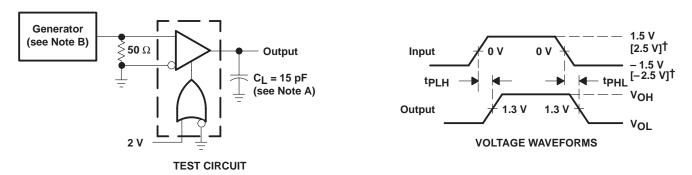
NOTE 3: Refer to TIA/EIA-422-B and TIA/EIA-423-B for exact conditions.

switching characteristics, $V_{CC} = 5 \text{ V}$, $T_A = 25^{\circ}\text{C}$

PARAMETER		TEST CONDITIONS		MIN	TYP	MAX	UNIT
tPLH	Propagation delay time, low-to-high-level output	$V_{ID} = -1.5 \text{ V to } 1.5 \text{ V},$			20	35	ns
tPHL	Propagation delay time, high-to-low-level output	$C_L = 15 pF$,	See Figure 1		22	35	ns
tPZH	Output enable time to high level	$C_L = 15 pF$,	See Figure 2		17	22	ns
tpzL	Output enable time to low level	$C_L = 15 pF$,	See Figure 3		20	25	ns
tPHZ	Output disable time from high level	$C_L = 5 pF$,	See Figure 2		21	30	ns
tPLZ	Output disable time from low level	$C_L = 5 pF$,	See Figure 3		30	40	ns

[†] All typical values are at V_{CC} = 5 V, T_A = 25°C. ‡ The algebraic convention, in which the less positive (more negative) limit is designated as minimum, is used in this data sheet for threshold voltage levels only.

PARAMETER MEASUREMENT INFORMATION

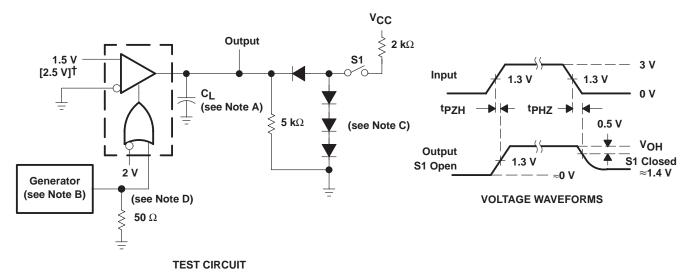


[†] Voltage for the SN55173 only.

NOTES: A. C_L includes probe and jig capacitance.

B. The input pulse is supplied by a generator having the following characteristics: PRR = 1 MHz, duty cycle = 50%, $t_{\Gamma} \le 6$ ns, $t_{\Gamma} \le 6$

Figure 1. tplH, tpHL Test Circuit and Voltage Waveforms



† Voltage for the SN55173 only.

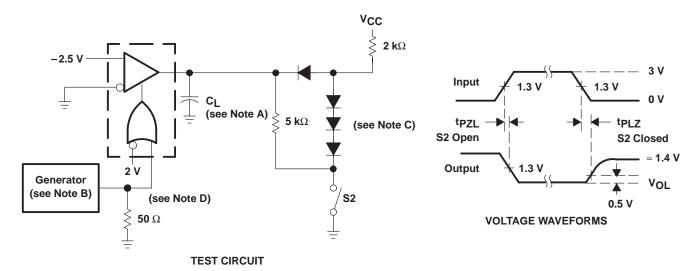
NOTES: A. C_L includes probe and jig capacitance.

- B. The input pulse is supplied by a generator having the following characteristics: PRR = 1 MHz, duty cycle = 50%, $t_r \le 6$ ns, $t_f \le 6$ ns
- C. All diodes are 1N916, or equivalent.
- D. To test the active-low enable \overline{G} , ground G and apply an inverted input waveform to \overline{G} .

Figure 2. t_{PHZ}, t_{PZH} Test Circuit and Voltage Waveforms



PARAMETER MEASUREMENT INFORMATION

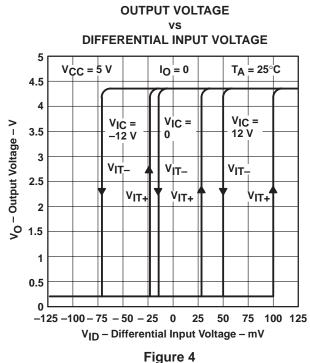


NOTES: A. C_L includes probe and jig capacitance.

- B. The input pulse is supplied by a generator having the following characteristics: PRR = 1 MHz, duty cycle = 50%, $t_f \le 6$ ns, $t_f \le 6$ ns
- C. All diodes are 1N916, or equivalent.
- D. To test the active-low enable \overline{G} , ground G and apply an inverted input waveform to \overline{G} .

Figure 3. tpzl, tpLZ Test Circuit and Voltage Waveforms

TYPICAL CHARACTERISTICS[†]



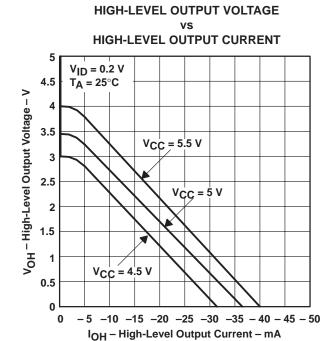
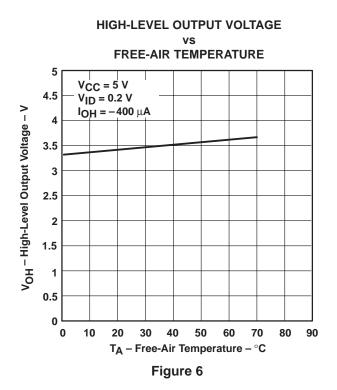


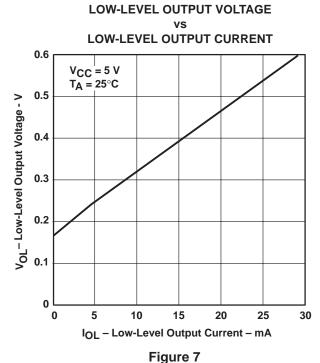
Figure 5

[†] Operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied.

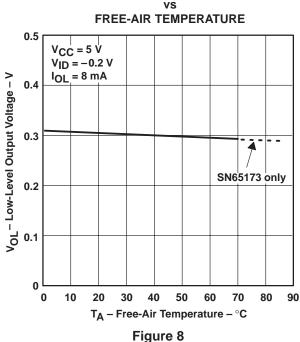


TYPICAL CHARACTERISTICS†

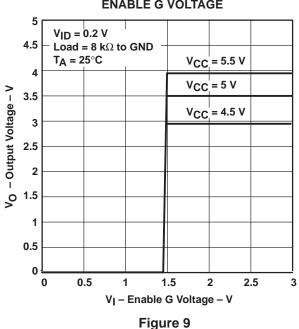




LOW-LEVEL OUTPUT VOLTAGE
vs
FREE-AIR TEMPERATURE



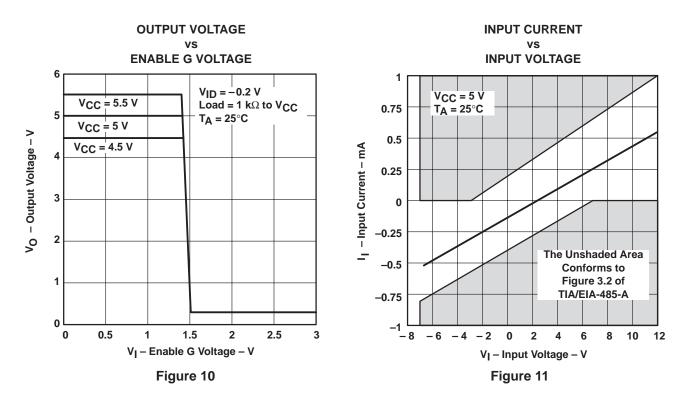
OUTPUT VOLTAGE vs ENABLE G VOLTAGE



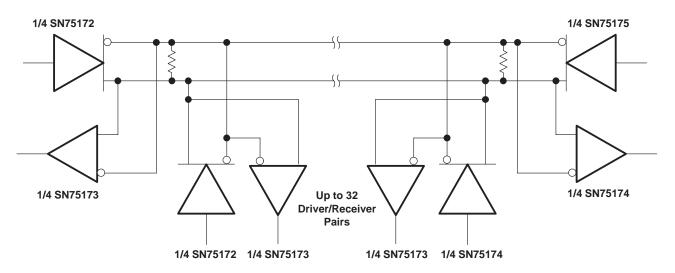
[†] Operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied.



TYPICAL CHARACTERISTICS



APPLICATION INFORMATION



NOTE A: The line should be terminated at both ends in its characteristic impedance. Stub lengths off the main line should be kept as short as possible.

Figure 12. Typical Application Circuit



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